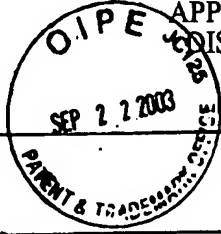


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	July 10, 2003	unknown



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Examiner Initial	Document No.	Date	Name	Filing Date If Appropriate
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OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

This page already considered, see attached

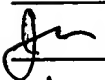

EXAMINER: *[Signature]*

DATE CONSIDERED: 12/22/03

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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	5,056,098	10/08/1991	Anthony et al.			
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
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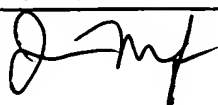
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


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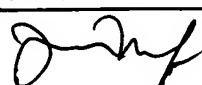
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	5,995,531	11/30/1999	Gaw et al.			
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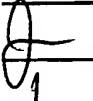

Def 12/22/03

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Examiner Initial	Document No.	Date	Name	Class	Sub Class	Filing Date If Appropriate
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	6,043,104	03/28/2000	Uchida et al.			
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


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	6,459,713	10/01/2002	Jewell			
	6,462,360	10/08/2002	Higgins, Jr. et al.			
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








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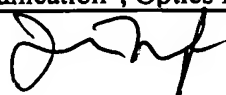
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










 12/22/05

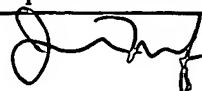
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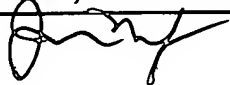
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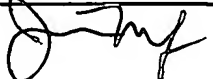
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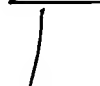










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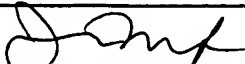
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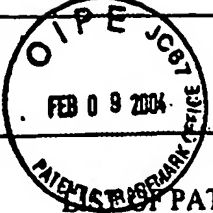
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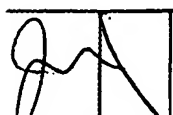
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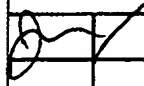
IDS: 9/29/03

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	Applicant: Ralph Johnson et al.		
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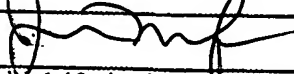
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